

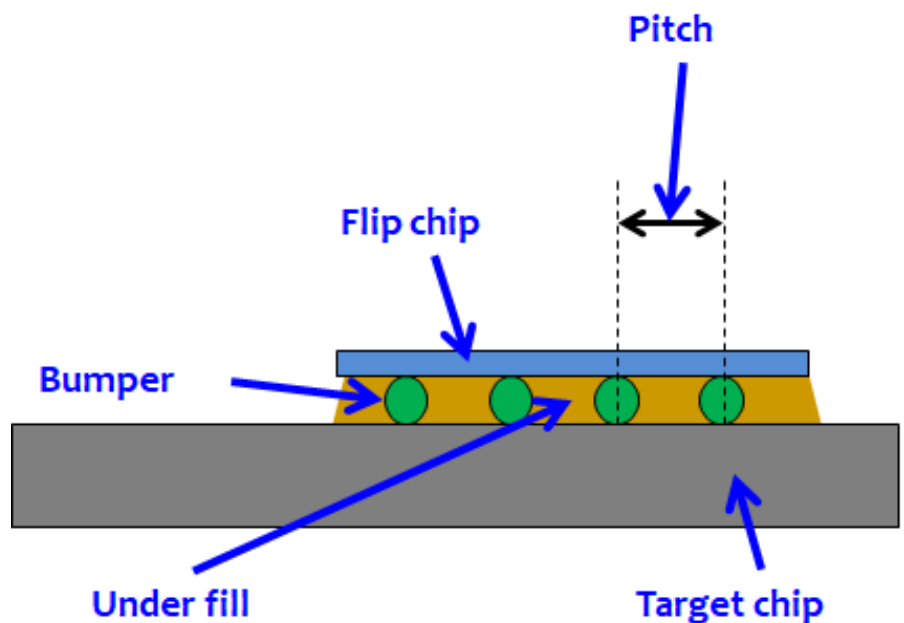
Flip-Chip Bonding Service



State-of-the-art Flip-Chip Bonding Equipment in 1000 m² (class 1000) clean room

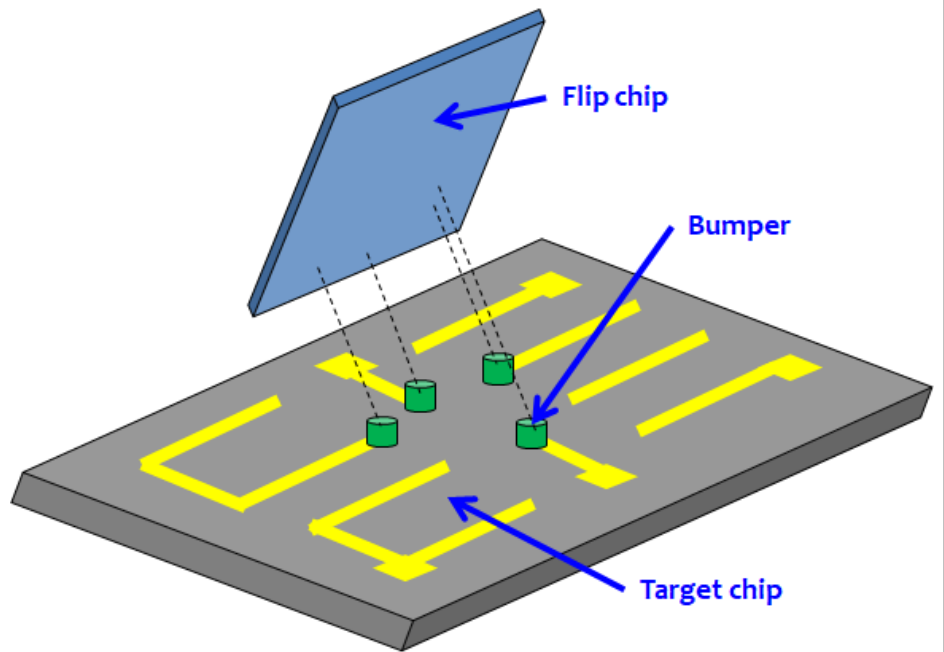
Capability

- Minimum pitch: 10 μ m
- Component size:
Flip chip: 200 μ m ~ 60mm
Target chip: 500 μ m ~ 150mm
- Gold, Gold/Tin, Indium, Polymers and adhesive
- Compound semiconductors
Si-based device or substrate

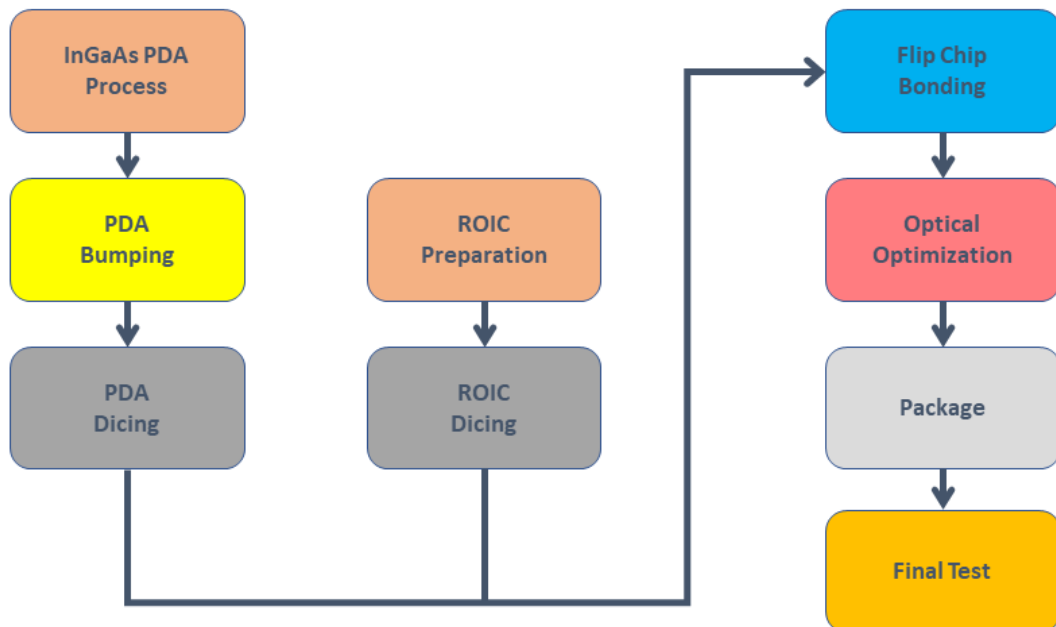


Applications

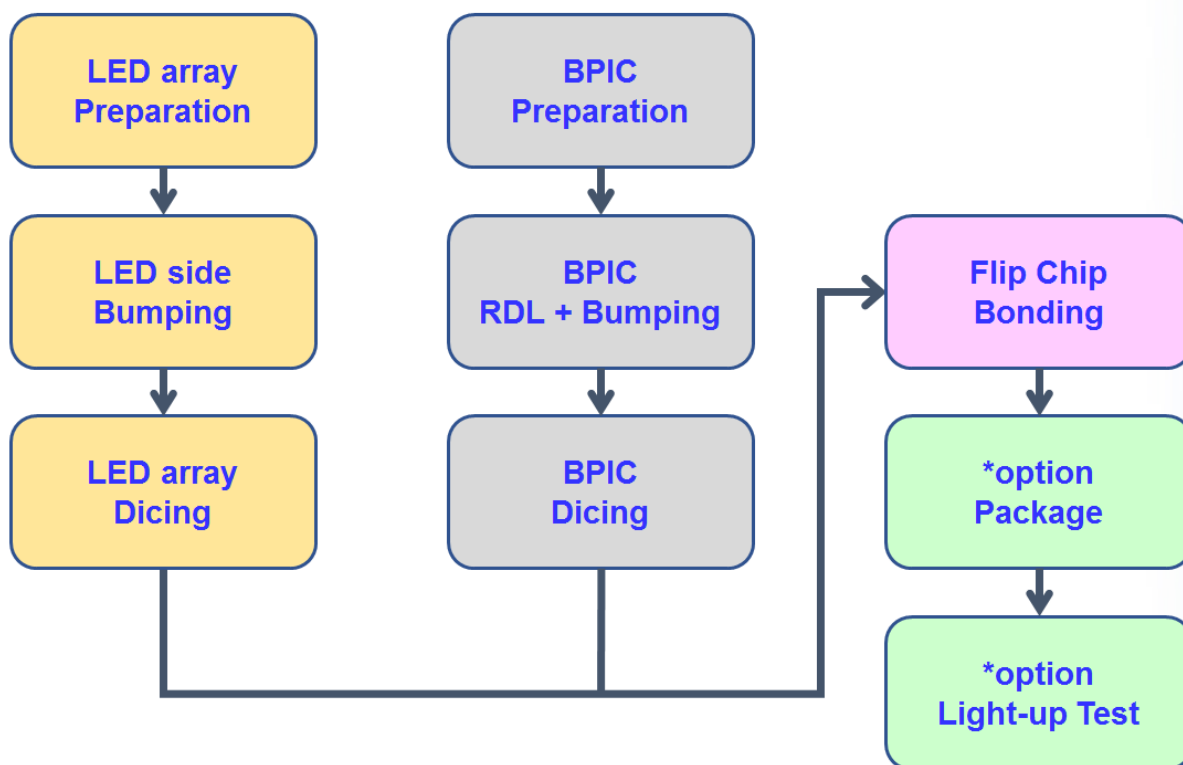
- MEMS
- Focal Plane Array
- Chip to substrate
- 3D IC
- BGA
- μ LED
- Chip Stacking



Process Steps of FPA



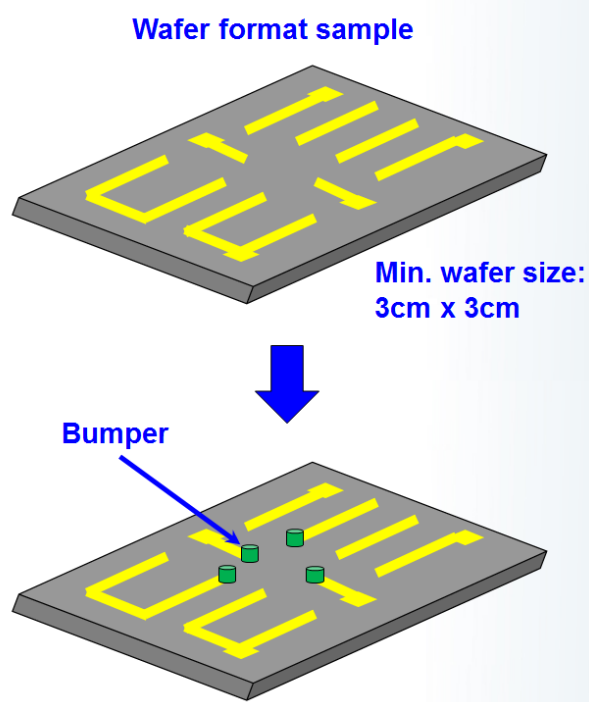
Process Steps of μ LED Panel



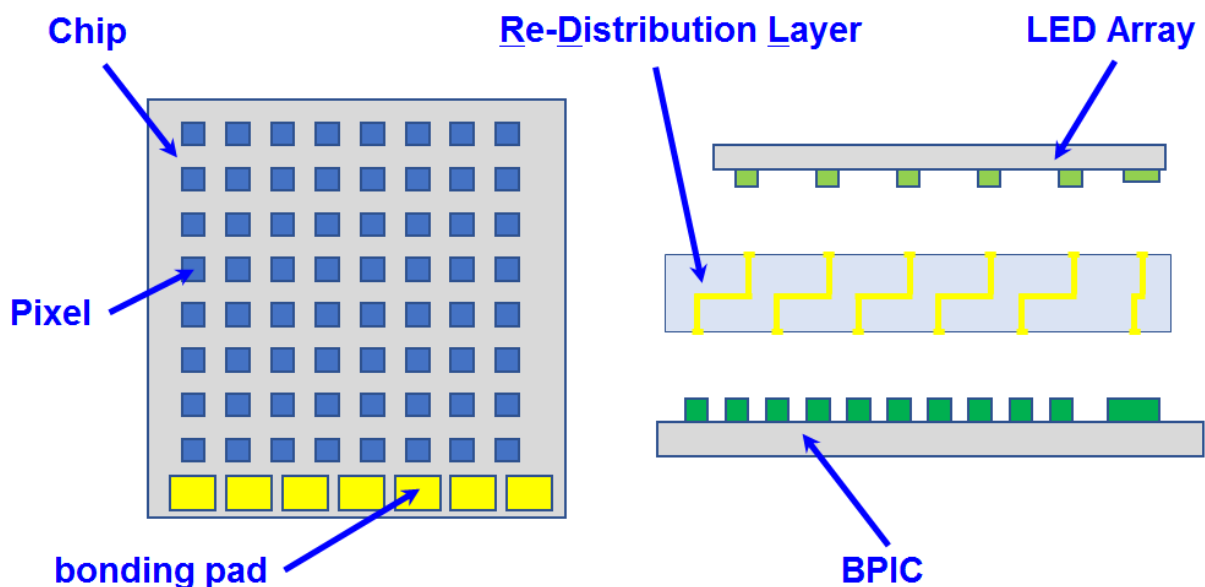
Bumping Process

Bumping process is essential to Flip-Chip Bonding.

Bumping is an advanced wafer level process technology where “bumpers” made of solder are formed on the wafers in a wafer form before the wafer is being diced into individual chips



Re-Distribution Layer



RDL is an interface to connect 2 arrays with different pixel pitch.